Listing of the Claims:

The following is a complete listing of all the claims in the application, with an indication of the status of each:

1. (Currently amended) A method of producing a carbon nanotube, comprising:

preparing a carbon nanotube by one dimensional carbon structure;

introducing a catalyst substance into a said one dimensional carbon

structure;

making said catalyst substance move in said <u>one dimensional</u> carbon structure; and

crystallizing a trail region of movement of said catalyst in said <u>one</u>
dimensional carbon structure, wherein said step of crystallizing converts said trail region to said a carbon nanotube.

- 2. (Currently amended) The method of producing a carbon nanotube according to claim 1, wherein said crystallizing said trail region is performed after said <u>one dimensional</u> carbon structure is fixed on a predetermined position of a substrate.
- 3. (Currently amended) The method of producing a carbon nanotube according to claim 1, wherein said carbon structure is heated when said catalyst substance is moved in said one dimensional carbon structure.
- 4. (Currently amended) The method of producing a carbon nanotube according to claim 3, wherein at least a part of said catalyst substance is liquefied by heating said one dimensional carbon structure.
- 5. (Currently amended) The method of producing a carbon nanotube according to claim 1, wherein said one dimensional carbon structure is formed by a vapor-phase deposition method of using a charged particle beam as an excitation source.
- 6. (Currently amended) The method of producing a carbon nanotube according to claim 1, wherein said one dimensional carbon structure is prepared by a

vapor-phase deposition method of using an aromatic hydrocarbon compound as a precursor material.

- 7. Currently amended) The method of producing a carbon nanotube according to claim 1, wherein said one dimensional carbon structure is a resist pattern.
- 8. (Currently amended) The method of producing a carbon nanotube according to claim 1, wherein said <u>one dimensional</u> carbon structure is a linear structure and said catalyst substance is moved along said <u>one dimensional</u> carbon structure.
- 9. (Previously presented) The method of producing a carbon nanotube according to claim 8, wherein said catalyst substance is a catalyst particle and the diameter of said catalyst particle is 0.5 to 3 times as large as the diameter of said linear structure.
- 10. (Currently amended) A method of producing a carbon nanotube, comprising: preparing a substrate;

forming a <u>one dimensional</u> carbon structure at a position separated from a surface of the substrate;

preparing a carbon nanotube by making a catalyst substance move in the one dimensional carbon structure; and

crystallizing a trail region of movement of said catalyst in said <u>one</u>

<u>dimensional</u> carbon structure, wherein said step of crystallizing converts said trail region to said carbon nanotube.

- 11. (Currently amended) The method of producing a carbon nanotube according to claim 10, wherein said <u>one dimensional</u> carbon structure is heated when said catalyst substance is moved in the carbon structure.
- 12. (Currently amended) The method of producing a carbon nanotube according to claim 11, wherein at least part of said catalyst substance is liquefied by heating said one dimensional carbon structure.

- 13. (Currently amended) The method of producing a carbon nanotube according to claim 10, wherein said <u>one dimensional</u> carbon structure is formed by a vapor-phase deposition method of using a charged particle beam as an excitation source.
- 14. (Currently amended) The method of producing a carbon nanotube according to claim 10, wherein said <u>one dimensional</u> carbon structure is prepared by a vapor-phase deposition method of using an aromatic hydrocarbon compound as a precursor material.
- 15. (Currently amended) The method of producing a carbon nanotube according to claim 10, wherein said <u>one dimensional</u> carbon structure is a resist pattern.
- 16. (Currently amended) A method of producing a transistor, comprising forming a carbon nanotube structure by

introducing a catalyst substance into a <u>one dimensional</u> carbon structure; making said catalyst substance move in said <u>one dimensional</u> carbon structure; and

crystallizing a trail region of movement of said catalyst in said <u>one</u>

<u>dimensional</u> carbon structure, wherein said step of crystallizing converts said trail region to said carbon nanotube structure;

forming a source electrode and a drain electrode on both ends of said carbon nanotube structure, respectively; and

forming a gate electrode on said carbon nanotube structure.

17. (Currently amended) A method of producing a wiring structure of carbon nanotube, comprising

forming a carbon nanotube structure by

introducing a catalyst substance into a <u>one dimensional</u> carbon structure;

making said catalyst substance move in said <u>one dimensional</u> carbon structure; and

crystallizing a trail region of movement of said catalyst in said one

<u>dimensional</u> carbon structure, wherein said step of crystallizing converts said trail region to a carbon nanotube.

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24. (Currently amended) A method of producing a transistor, comprising forming a carbon nanotube structure by

preparing a substrate;

forming a <u>one dimensional</u> carbon structure at a position separated from a surface of said substrate;

preparing a carbon nanotube by making a catalyst substance move in said <u>one dimensional</u> carbon structure; and crystallizing a trail region of movement of said catalyst in said <u>one dimensional</u> carbon structure, wherein said step of crystallizing converts said trail region to said carbon nanotube structure;

forming a source electrode and a drain electrode on both ends of said carbon nanotube structure, respectively; and

forming a gate electrode on said carbon nanotube structure.

25. (Currently amended) A method of producing a wiring structure of carbon nanotube, comprising

forming a carbon nanotube by

preparing a substrate;

forming a <u>one dimensional</u> carbon structure at a position separated from a surface of said substrate;

preparing a carbon nanotube by making a catalyst substance move in said <u>one dimensional</u> carbon structure; and crystallizing a trail region of movement of said catalyst in said carbon structure, wherein said step of crystallizing converts said trail region to said carbon nanotube.